

Data Sheet November 14, 2002 FN7045

Ultra-Low Noise, Low Power, Wideband Amplifier



The EL2125 is an ultra-low noise, wideband amplifier that runs on half the supply current of competitive parts.

It is intended for use in systems such as ultrasound imaging where a very small signal needs to be amplified by a large amount without adding significant noise. Its low power dissipation enables it to be packaged in the tiny SOT-23 package, which further helps systems where many input channels create both space and power dissipation problems.

The EL2125 is stable for gains of 10 and greater and uses traditional voltage feedback. This allows the use of reactive elements in the feedback loop, a common requirement for many filter topologies. It operates from ±2.5V to ±15V supplies and is available in the 5-pin SOT-23 and 8-pin SO packages.

The EL2125 is fabricated using Elantec's proprietary complementary bipolar process, and is specified for operation from -45°C to +85°C.

Features

- Voltage noise of only 0.83nV/√Hz
- Current noise of only 2.4pA/√Hz
- 200µV offset voltage
- 175MHz -3dB BW for A_V=10
- Low supply current 10mA
- SOT-23 package available
- ±2.5V to ±15V operation

Applications

- · Ultrasound input amplifiers
- · Wideband instrumentation
- · Communication equipment
- · AGC & PLL active filters
- · Wideband sensors

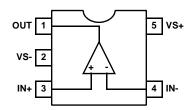
Ordering Information

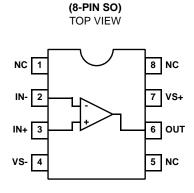
| PART NUMBER | PACKAGE | TAPE & REEL | PKG. NO. |
|--------------|---------------|----------------|----------|
| EL2125CW-T7 | 5-Pin SOT-23* | 7" | MDP0038 |
| EL2125CW-T13 | 5-Pin SOT-23* | 13" | MDP0038 |
| EL2125CS | 8-Pin SO | - | MDP0027 |
| EL2125CS-T7 | 8-Pin SO | 7" | MDP0027 |
| EL2125CS-T13 | 8-Pin SO | 13" | MDP0027 |

^{*}EL2125CW symbol is .Fxxx where xxx represents date code

Pinouts

EL2125 (**5-PIN SOT-23**) TOP VIEW





EL2125

EL2125

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

Electrical Specifications $V_S = \pm 5V$, $T_A = 25^{\circ}C$, $R_F = 180\Omega$, $R_G = 20\Omega$, $R_L = 500\Omega$ unless otherwise specified.

| PARAMETER | DESCRIPTION | CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------|---|--|------|-------|------|--------|
| DC PERFORM | ANCE | | l | | I. | 1 |
| V _{OS} | Input Offset Voltage (SO8) | | | 0.2 | 2 | mV |
| | Input Offset Voltage (SOT23-5) | | | | 3 | mV |
| T _{CVOS} | Offset Voltage Temperature Coefficient | | | 1.8 | | μV/°C |
| I _B | Input Bias Current | | -30 | -22 | | μΑ |
| I _{OS} | Input Bias Current Offset | | | 0.4 | 2 | μΑ |
| T _{CIB} | Input Bias Current Temperature Coefficient | | | 0.09 | | μΑ/°C |
| C _{IN} | Input Capacitance | | | 2.2 | | pF |
| A _{VOL} | Open Loop Gain | | 80 | 87 | | dB |
| PSRR | Power Supply Rejection Ratio (Note 1) | | 80 | 97 | | dB |
| CMRR | Common Mode Rejection Ratio | at CMIR | 80 | 106 | | dB |
| CMIR | Common Mode Input Range | | -4.6 | | 3.8 | V |
| V _{OUTH} | Output Voltage Swing High | No load, $R_F = 1k\Omega$ | 3.5 | 3.65 | | V |
| V _{OUTL} | Output Voltage Swing Low | No load, $R_F = 1k\Omega$ | | -3.87 | -3.7 | V |
| V _{OUTH2} | Output Voltage Swing High | $R_L = 100\Omega$ | 3 | 3.3 | | V |
| V _{OUTL2} | Output Voltage Swing Low | $R_L = 100\Omega$ | | -3.5 | -3 | V |
| I _{OUT} | Output Short Circuit Current (Note 2) | | 80 | 100 | | mA |
| IS | Supply Current | | | 10.1 | 11 | mA |
| AC Performan | ce - R _G = 20Ω, C _L = 5pF | | | | • | |
| BW | -3dB Bandwidth | | | 175 | | MHz |
| BW ±0.1dB | ±0.1dB Bandwidth | | | 34 | | MHz |
| BW ±1dB | ±1dB Bandwidth | | | 150 | | MHz |
| Peaking | Peaking | | | 0.4 | | dB |
| SR | Slew Rate | V _{OUT} = 2V _{PP} , measured at 20% to 80% | 150 | 185 | | V/µs |
| OS | Overshoot, 4Vpk-pk Output Square | Positive | | 0.6 | | % |
| | Wave | Negative | | 2.7 | | % |
| t _S | Settling Time to 0.1% of ±1V Pulse | | | 42 | | ns |
| V_N | Voltage Noise Spectral Density | | | 0.83 | | nV/√Hz |

Electrical Specifications $V_S = \pm 5V$, $T_A = 25$ °C, $R_F = 180\Omega$, $R_G = 20\Omega$, $R_L = 500\Omega$ unless otherwise specified. (Continued)

| PARAMETER | DESCRIPTION CONDITIONS | | MIN | TYP | MAX | UNIT |
|----------------|----------------------------------|--|-----|-----|-----|--------|
| I _N | Current Noise Spectral Density | | | 2.4 | | pA/√Hz |
| HD2 | 2nd Harmonic Distortion (Note 3) | | | -74 | | dBc |
| HD3 | 3rd Harmonic Distortion | | | -91 | | dBc |

NOTES:

- 1. Measured by moving the supplies from $\pm 4V$ to $\pm 6V$
- 2. Pulse test only
- 3. Frequency = 1MHz, $V_{\mbox{OUT}}$ = 2Vpk-pk, into 500Ω and 5pF load

Electrical Specifications $V_S = \pm 15V$, $T_A = 25$ °C, $R_F = 180\Omega$, $R_G = 20\Omega$, $R_L = 500\Omega$ unless otherwise specified.

| PARAMETER | R DESCRIPTION CONDITIONS | | MIN | TYP | MAX | UNIT |
|--------------------|---|--|-------|-------|------|-------|
| DC PERFORM | ANCE | | * | | | |
| V _{OS} | Input Offset Voltage (SO8) | | | 0.6 | 3 | mV |
| | Input Offset Voltage (SOT23-5) | | | | 3 | mV |
| T _{CVOS} | Offset Voltage Temperature Coefficient | | | 4.9 | | μV/°C |
| I _B | Input Bias Current | | -30 | -24 | | μA |
| los | Input Bias Current Offset | | | 0.4 | 2 | μA |
| T _{CIB} | Input Bias Current Temperature Coefficient | | | 0.08 | | μΑ/°C |
| C _{IN} | Input Capacitance | | | 2.2 | | pF |
| A _{VOL} | Open Loop Gain | | 80 | 87 | | dB |
| PSRR | Power Supply Rejection Ratio (Note 1) | | 80 | 97 | | dB |
| CMRR | Common Mode Rejection Ratio | at CMIR | 75 | 105 | | dB |
| CMIR | Common Mode Input Range | | -14.6 | | 13.8 | V |
| V _{OUTH} | Output Voltage Swing High | No load, $R_F = 1k\Omega$ | 13.35 | 13.5 | | V |
| V _{OUTL} | Output Voltage Swing Low | No load, $R_F = 1k\Omega$ | | -13.6 | -13 | V |
| V _{OUTH2} | Output Voltage Swing High | $R_L = 100\Omega$ | 11 | 11.6 | | V |
| V _{OUTL2} | Output Voltage Swing Low | $R_L = 100\Omega$ | | -10.4 | -9.8 | V |
| lout | Output Short Circuit Current (Note 2) | | 120 | 250 | | mA |
| I _S | Supply Current | | | 10.8 | 12 | mA |
| AC Performan | ce - R _G = 20Ω, C _L = 5pF | | | * | | ! |
| BW | -3dB Bandwidth | | | 220 | | MHz |
| BW ±0.1dB | ±0.1dB Bandwidth | | | 23 | | MHz |
| BW ±1dB | ±1dB Bandwidth | | | 63 | | MHz |
| Peaking | Peaking | | | 2.5 | | dB |
| SR | Slew Rate | V _{OUT} = 2V _{PP} , measured at 20% to 80% | 180 | 225 | | V/µs |
| os | Overshoot, 4Vpk-pk Output Square Wave | | | 0.6 | | % |
| t _S | Settling Time to 0.1% of ±1V Pulse | | | 38 | | ns |

EL2125

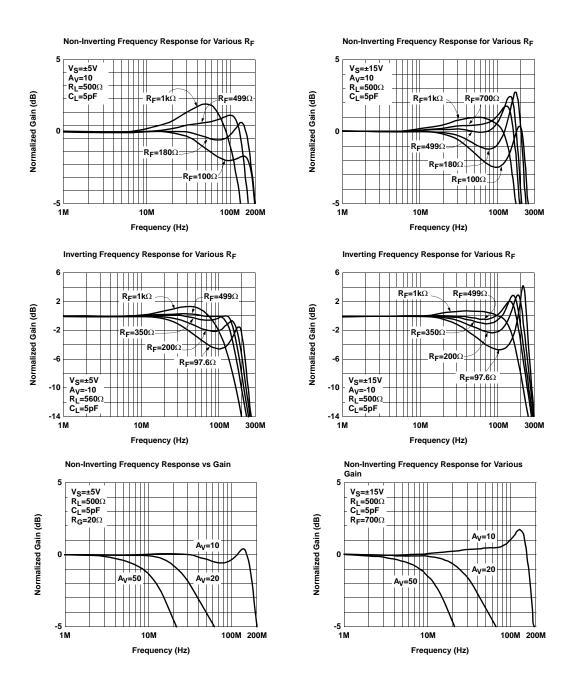
Electrical Specifications $V_S = \pm 15 \text{V}, T_A = 25 ^{\circ}\text{C}, R_F = 180 \Omega, R_G = 20 \Omega, R_L = 500 \Omega$ unless otherwise specified. **(Continued)**

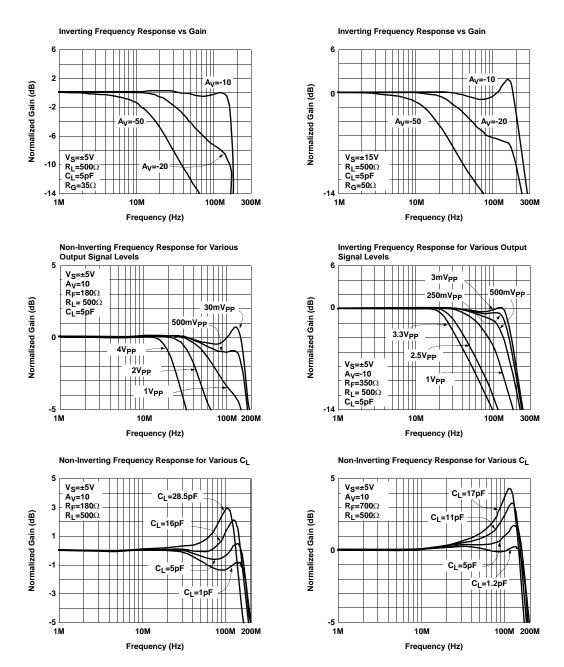
| PARAMETER | DESCRIPTION CONDITIONS | | MIN | TYP | MAX | UNIT |
|----------------|----------------------------------|--|-----|------|--------|--------|
| V _N | Voltage Noise Spectral Density | | | 0.95 | | nV/√Hz |
| I _N | Current Noise Spectral Density | | 2.1 | | pA/√Hz | |
| HD2 | 2nd Harmonic Distortion (Note 3) | | | -73 | | dBc |
| HD3 | 3rd Harmonic Distortion | | | -96 | | dBc |

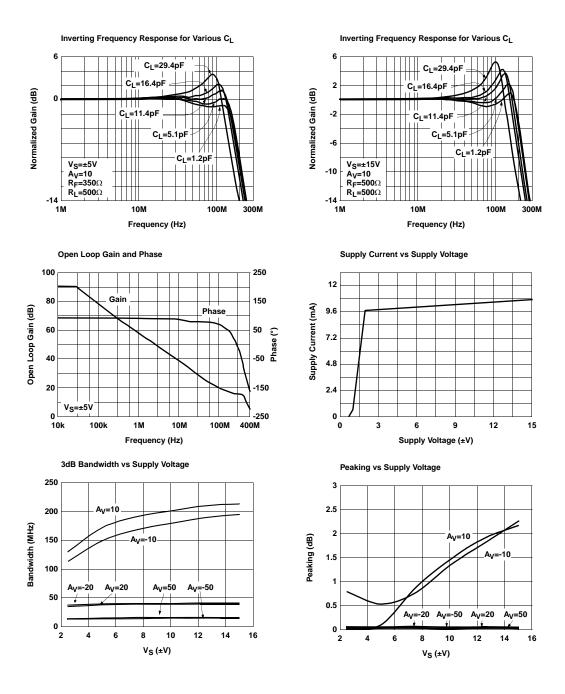
NOTES:

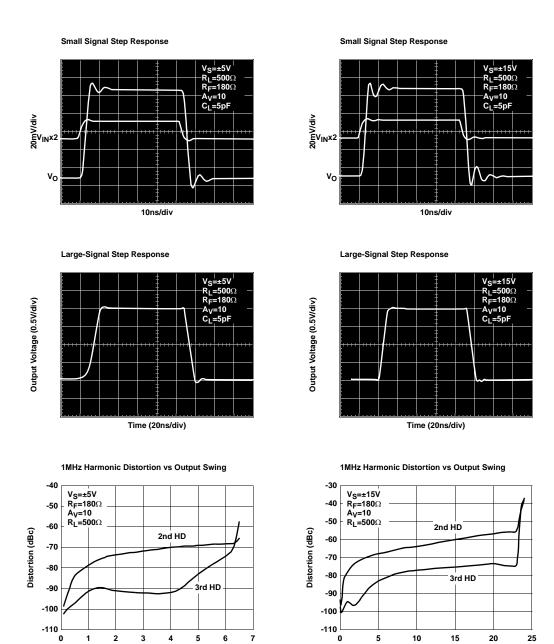
- 1. Measured by moving the supplies from $\pm 13.5 \text{V}$ to $\pm 16.5 \text{V}$
- 2. Pulse test only
- 3. Frequency = 1MHz, V_{OUT} = 2Vpk-pk, into 500Ω and 5pF load

Typical Performance Curves



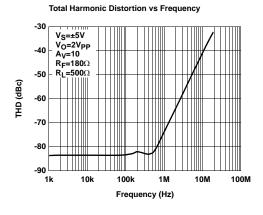


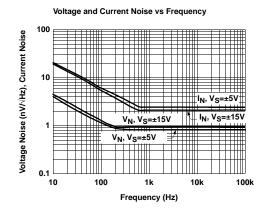


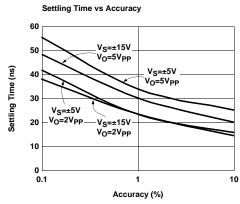


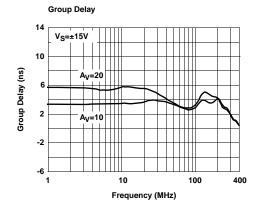
V_{OUT} (V_{PP})

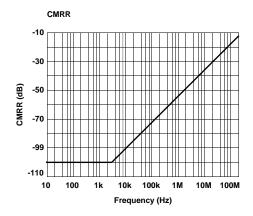
V_{OUT} (V_{PP})

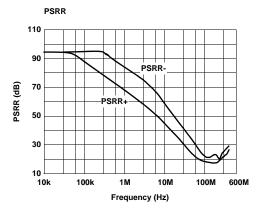


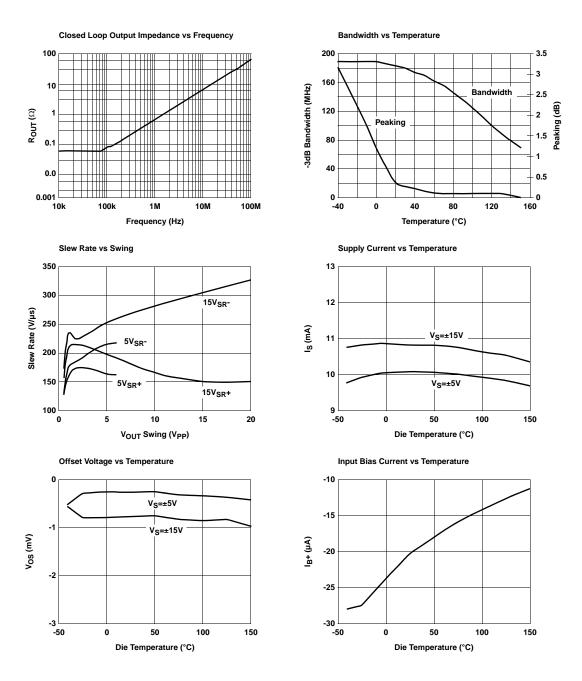


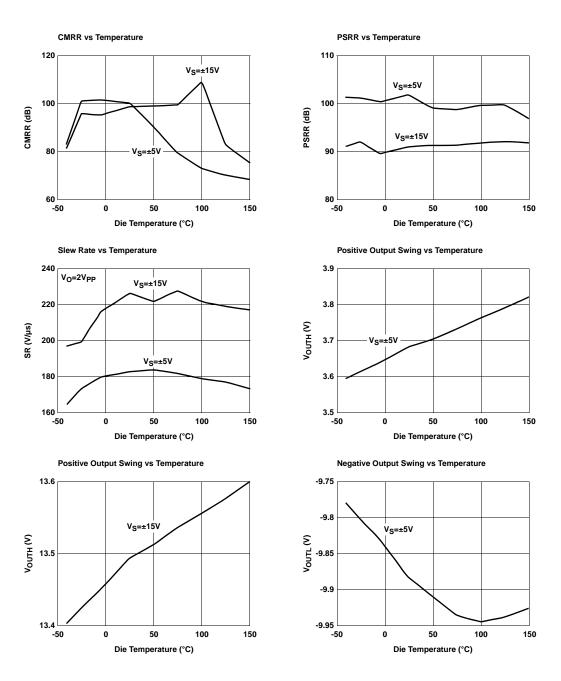


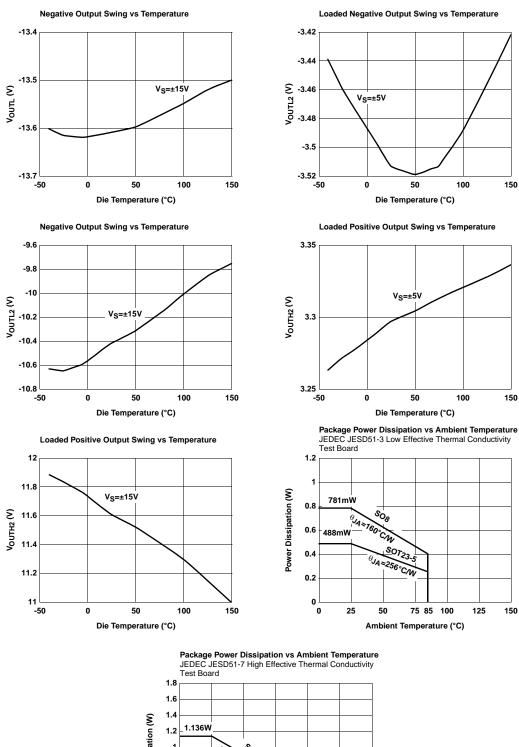












Pin Descriptions

| EL2125CW (5-PIN SOT-23) | EL2125CS (8-PIN SO) | PIN NAME | PIN FUNCTION | EQUIVALENT CIRCUIT |
|----------------------------|------------------------|----------|--------------|---|
| 1 | 6 | VOUT | Output | V _S + V _{OUT} Vircuit 1 |
| 2 | 4 | VS- | Supply | |
| 3 | 3 | VINA+ | Input | V _{IN} + V _{IN} - V _{IN} - Circuit 2 |
| 4 | 2 | VINA- | Input | Reference Circuit 2 |
| 5 | 7 | VS+ | Supply | |

Applications Information

Product Description

The EL2125 is an ultra-low noise, wideband monolithic operational amplifier built on Elantec's proprietary high speed complementary bipolar process. It features 0.83nV/ $\sqrt{\text{Hz}}$ input voltage noise, 200 μ V offset voltage, and 73dB THD. It is intended for use in systems such as ultrasound imaging where very small signals are needed to be amplified. The EL2125 also has excellent DC specifications: 200 μ V VOS, 22 μ A IB, 0.4 μ A IOS, and 106dB CMRR. These specifications allow the EL2125 to be used in DC-sensitive applications such as difference amplifiers.

Gain-Bandwidth Product

The EL2125 has a gain-bandwidth product of 800MHz at ±5V. For gains greater than 20, its closed-loop -3dB bandwidth is approximately equal to the gain-bandwidth product divided by the small signal gain of the circuit. For gains less than 20, higher-order poles in the amplifier's transfer function contribute to even higher closed-loop bandwidths. For example, the EL2125 has a -3dB bandwidth of 175MHz at a gain of 10 and decreases to 40MHz at gain of 20. It is important to note that the extra bandwidth at lower gain does not come at the expenses of stability. Even though the EL2125 is designed for gain > 10 with external

compensation, the device can also operate at lower gain settings. The RC network shown in Figure 1 reduces the feedback gain at high frequency and thus maintains the amplifier stability. R values must be less than RF divided by 9 and 1 divided by 2π RC must be less than 400MHz.

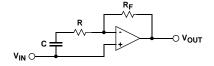


FIGURE 1.

Choice of Feedback Resistor, RF

The feedback resistor forms a pole with the input capacitance. As this pole becomes larger, phase margin is reduced. This increases ringing in the time domain and peaking in the frequency domain. Therefore, RF has some maximum value which should not be exceeded for optimum performance. If a large value of RF must be used, a small capacitor in the few pF range in parallel with RF can help to reduce this ringing and peaking at the expense of reducing the bandwidth. Frequency response curves for various RF values are shown the in typical performance curves section of this data sheet.

Noise Calculations

The primary application for the EL2125 is to amplify very small signals. To maintain the proper signal-to-noise ratio, it is essential to minimize noise contribution from the amplifier. Figure 2 below shows all the noise sources for all the components around the amplifier.

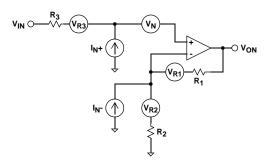


FIGURE 2.

 V_N is the amplifier input voltage noise I_{N^+} is the amplifier positive input current noise I_{N^-} is the amplifier negative input current noise V_{RX} is the thermal noise associated with each resistor:

$$V_{RX} = \sqrt{4kTRx}$$

where:

k is Boltzmann's constant = 1.380658×10^{-23}

T is temperature in degrees Kelvin (273+ °C)

The total noise due to the amplifier seen at the output of the amplifier can be calculated by using the equation below (Figure 3).

As the equation shows, to keep noise at a minimum, small resistor values should be used. At higher amplifier gain configuration where R_2 is reduced, the noise due to IN-, R_2 , and R_1 decreases and the noise caused by IN+, VN, and R_3 starts to dominate. Because noise is summed in a root-mean-squares method, noise sources smaller than 25% of the largest noise source can be ignored. This can greatly simplify the formula and make noise calculation much easier to calculate.

Output Drive Capability

The EL2125 is designed to drive low impedance load. It can easily drive $6V_{P-P}$ signal into a 100Ω load. This high output drive capability makes the EL2125 an ideal choice for RF, IF, and video applications. Furthermore, the EL2125 is current-

limited at the output, allowing it to withstand momentary short to ground. However, the power dissipation with output-shorted cannot exceed the power dissipation capability of the package.

Driving Cables and Capacitive Loads

Although the EL2125 is designed to drive low impedance load, capacitive loads will decrease the amplifier's phase margin. As shown the in the performance curves, capacitive load can result in peaking, overshoot and possible oscillation. For optimum AC performance, capacitive loads should be reduced as much as possible or isolated with a series resistor between 5Ω to 20Ω . When driving coaxial cables, double termination is always recommended for reflection-free performance. When properly terminated, the capacitance of the coaxial cable will not add to the capacitive load seen by the amplifier.

Power Supply Bypassing And Printed Circuit Board Layout

As with any high frequency devices, good printed circuit board layout is essential for optimum performance. Ground plane construction is highly recommended. Lead lengths should be kept as short as possible. The power supply pins must be closely bypassed to reduce the risk of oscillation. The combination of a 4.7 μ F tantalum capacitor in parallel with 0.1 μ F ceramic capacitor has been proven to work well when placed at each supply pin. For single supply operation, where pin 4 (V_S-) is connected to the ground plane, a single 4.7 μ F tantalum capacitor in parallel with a 0.1 μ F ceramic capacitor across pins 7 (V_S+) and pin 4 (V_S-) will suffice.

For good AC performance, parasitic capacitance should be kept to a minimum. Ground plane construction again should be used. Small chip resistors are recommended to minimize series inductance. Use of sockets should be avoided since they add parasitic inductance and capacitance which will result in additional peaking and overshoot.

Supply Voltage Range and Single Supply Operation

The EL2125 has been designed to operate with supply voltage range of ± 2.5 V to ± 15 V. With a single supply, the EL2125 will operate from ± 5 V to ± 30 V. Pins 4 and 7 are the power supply pins. The positive power supply is connected to pin 7. When used in single supply mode, pin 4 is connected to ground. When used in dual supply mode, the negative power supply is connected to pin 4.

As the power supply voltage decreases from +30V to +5V, it becomes necessary to pay special attention to the input

$$V_{ON} = \sqrt{BW} \times \sqrt{\left(VN^2 \times \left(1 + \frac{R_1}{R_2}\right)^2 + IN^{-2} \times {R_1}^2 + IN^{+2} \times {R_3}^2 \times \left(1 + \frac{R_1}{R_2}\right)^2 + 4 \times K \times T \times {R_1} + 4 \times K \times T \times {R_2} \times \left(\frac{R_1}{R_2}\right)^2 + 4 \times K \times T \times {R_3} \times \left(1 + \frac{R_1}{R_2}\right)^2\right)}$$

FIGURE 3.

voltage range. The EL2125 has an input voltage range of 0.4V from the negative supply to 1.2V from the positive supply. So, for example, on a single +5V supply, the EL2125 has an input voltage range which spans from 0.4V to 3.8V. The output range of the EL2125 is also quite large, on a +5V supply, it swings from 0.4V to 3.6V.

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